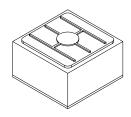
# **ODR1212TF.A2**

### OS-CORE® ThinGaAIP



#### Features:

- Polarity: n-side up

Chip technology: Thinfilm

- Color: • red

- Chipsize: 12 mil x 12 mil

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

## **Ordering Information**

Type Ordering Code
ODR1212TF.A2-MM-MM-1-C Q65111A9361



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
	- P	max.	110 °C
Storage Temperature 1)	$T_{stg}$	min.	-40 °C
	otg	max.	110 °C
Recommended Die Storage Temperature ≤ 60% RH	T <sub>stg die</sub>	max.	30 °C
Junction Temperature	T <sub>i</sub>	max.	125 °C
Junction temperature for short time applications*	T <sub>i</sub>	max.	150 °C
Forward Current	I <sub>F</sub>	min.	3 mA
$T_J = 25  ^{\circ}C$	•	max.	70 mA
Forward Current Pulsed $t \le 10 \ \mu s; D = 0.005 \ ; T_{_J} = 25 \ ^{\circ}C$	F pulse	max.	100 mA
Reverse voltage <sup>2)</sup> T <sub>J</sub> = 25 °C	$V_R$	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V <sub>ESD</sub>		2 kV

<sup>\*</sup>The median lifetime (L70/B50) for Tj =150 $^{\circ}$ C is 100h.

### **Characteristics**

T<sub>J</sub> = 25 °C

Parameter	Symbol		Values
Dominant Wavelength 3)	$\lambda_{\sf dom}$	min. max.	613.0 nm 639.5 nm
Forward Voltage 4)	V <sub>F</sub>	min. typ. max.	1.90 V 2.15 V 2.40 V

## **Additional Information**

Die bonding	Metalization frontside	Metalization backside
Adhesive bonding	Gold	Gold



## Binning Table 5)3)

Luminous Intensity Dominant Wavelength

$I_{v}$	$\lambda_{ ext{dom}}$
a. u.	nm

a. u.	nm				
	613.0 - 617.0	617.0 - 621.5	621.5 - 623.5	623.5 - 628.5	628.5 - 630.5
800 - 900	A10	B10	C10	D10	E10
900 - 1000	A13	B13	C13	D13	E13
1000 - 1140	A16	B16	C16	D16	E16
1140 - 1280	A19	B19	C19	D19	E19
1280 - 1440	A22	B22	C22	D22	E22
1440 - 1600	A25	B25	C25	D25	E25
1600 - 1800	A28	B28	C28	D28	E28
1800 - 2000	A31	B31	C31	D31	E31
2000 - 2250	A34	B34	C34	D34	E34
2250 - 2500	A37	B37	C37	D37	E37
2500 - 2850	A40	B40	C40	D40	E40
2850 - 3200	A43	B43	C43	D43	E43



#### ODR1212TF.A2

Luminous Intensity I <sub>v</sub> a. u.	Dominant Wavelength $\lambda_{\text{dom}}$ nm 630.5 - 635.0	635.0 - 639.5
800 - 900	F10	G10
900 - 1000	F13	G13
1000 - 1140	F16	G16
1140 - 1280	F19	G19
1280 - 1440	F22	G22
1440 - 1600	F25	G25
1600 - 1800	F28	G28
1800 - 2000	F31	G31
2000 - 2250	F34	G34
2250 - 2500	F37	G37
2500 - 2850	F40	G40
2850 - 3200	F43	G43

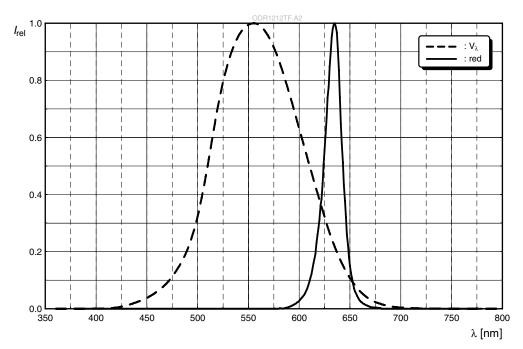
## Correlation factor 6)

Unit	Value	Condition
CF (mcd / a.u.)	1.08	chip to air
CF (mlm / a.u.)	5.01	chip with silicone lens



# Relative Spectral Emission 7)

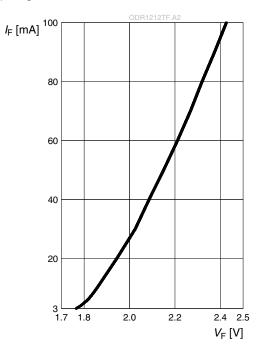
 $I_{rel} = f(\lambda); T_S = 25 \, ^{\circ}C$ 





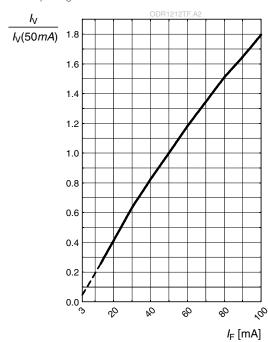
## Forward current 7), 8)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



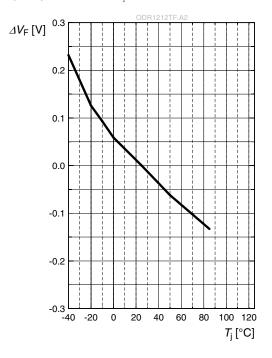
## Relative Luminous Intensity 7), 8)

$$I_{v}/I_{v}() = f(I_{F}); T_{S} = 25 \text{ }^{\circ}\text{C}$$



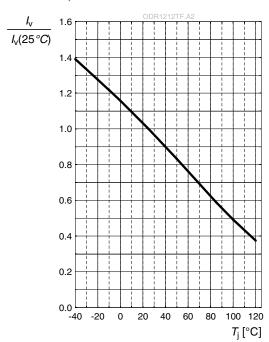
## Forward Voltage 7)

$$\Delta V_F = V_F - V_F (25 \text{ °C}) = f(T_j);$$



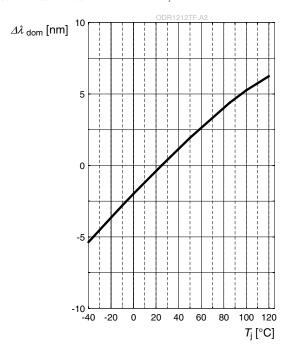
## Relative Luminous Intensity 7)

$$I_{v}/I_{v}(25 \text{ °C}) = f(T_{j});$$

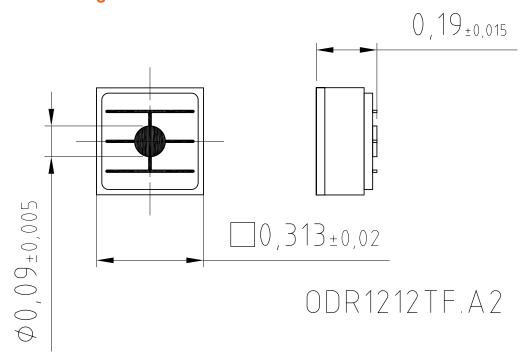


## Dominant Wavelength 7)

$$\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \, ^{\circ}C) = f(T_{j});$$



# **Dimensional Drawing** 9)





#### **Disclaimer**

#### Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

#### Attention please!

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Please use the recycling operators known to you. We can also help you – get in touch with your nearest

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#### Glossary

- Shelf life: Temperature refer solely to storage of finished LED product (Not valid for chip on die sheet).
- 2) Reverse Operation: Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- Wavelength: The wavelength is measured at a current pulse of typically 10 ms and with an internal reproducibility of  $\pm$  1 nm (with a coverage factor of k = 3).
- Forward Voltage: The forward voltage is measured during a current pulse of typically 5 ms and with an internal reproducibility of  $\pm$  0.1 V (with a coverage factor of k = 3).
- 5) Brightness: Brightness values are measured during a current pulse of typically 10 ms and with an internal reproducibility of  $\pm$  8 % (with a coverage factor of k = 3).
- 6) Correlation Factor: The exemplary correlation factor (CF) was estimated by sample build of the chip in a reference package and describes the exemplary correlation between the chip brightness measured in arbitrary units (a.u.) and the brightness in a reference package:  $CF = I/\Phi(package) / I(chip)$ . This factor is purely given as an indication of possible package brightness values. It may vary for different packages due to influences of geometries, reflectivity/refractive index of package materials or other material properties.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 9) Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.

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